# nexperia

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Should be replaced with:

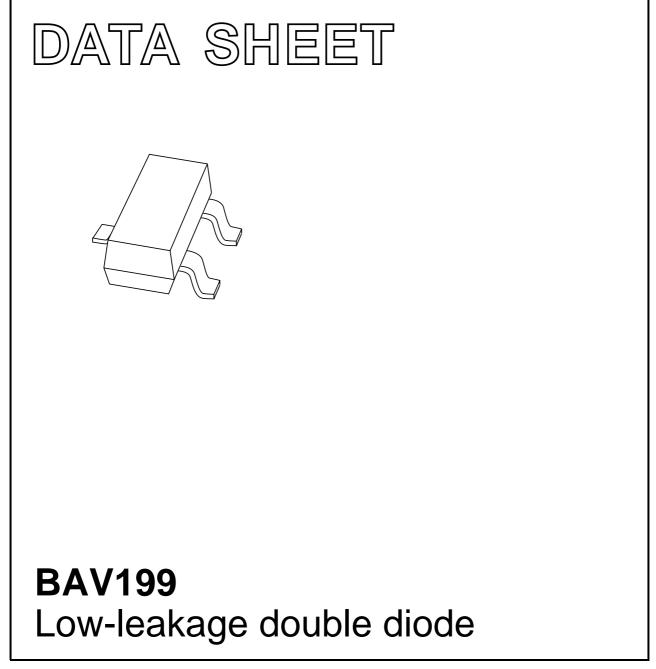
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

# DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 1999 May 11 2001 Oct 12



## FEATURES

- Plastic SMD package
- Low leakage current: typ. 3 pA
- Switching time: typ. 0.8 μs
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 85 V
- Repetitive peak forward current: max. 500 mA.

## APPLICATION

• Low-leakage current applications in surface mounted circuits.

## DESCRIPTION

Epitaxial, medium-speed switching, double diode in a small SOT23 plastic SMD package. The diodes are connected in series.

## MARKING

TYPE NUMBER	MARKING CODE <sup>(1)</sup>		
BAV199	JY*		

#### Note

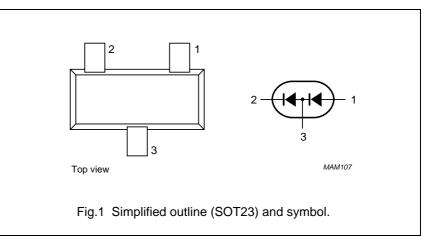
1. \* = p: Made in Hong Kong.

#### \* = t: Made in Malaysia.

\* = W: Made in China.

### PINNING

PIN	DESCRIPTION
1	anode
2	cathode
3	anode; cathode



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V <sub>RRM</sub>	repetitive peak reverse voltage		-	85	V
V <sub>R</sub>	continuous reverse voltage		-	75	V
I <sub>F</sub>	continuous forward current	single diode loaded; note 1; see Fig.2	-	160	mA
		double diode loaded; note 1; see Fig.2	-	140	mA
I <sub>FRM</sub>	repetitive peak forward current		-	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	square wave; T <sub>j</sub> = 25 °C prior to surge; see Fig.4			
		$t_p = 1 \ \mu s$	-	4	А
		t <sub>p</sub> = 1 ms	_	1	А
		t <sub>p</sub> = 1 s	-	0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	-	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

### Note

1. Device mounted on a FR4 printed-circuit board.

## Product data sheet

# **BAV199**

BAV199

## ELECTRICAL CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode		·			
V <sub>F</sub>	forward voltage	see Fig.3			
		I <sub>F</sub> = 1 mA	_	900	mV
		I <sub>F</sub> = 10 mA	_	1000	mV
		I <sub>F</sub> = 50 mA	_	1100	mV
		I <sub>F</sub> = 150 mA	-	1250	mV
I <sub>R</sub>	reverse current	see Fig.5			
		V <sub>R</sub> = 75 V	0.003	5	nA
		V <sub>R</sub> = 75 V; T <sub>j</sub> = 150 °C	3	80	nA
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	2	-	pF
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$ ; measured at $I_R = 1$ mA; see Fig.7	0.8	3	μs

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point		360	K/W
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W

#### Note

1. Device mounted on a FR4 printed-circuit board.

BAV199

#### **GRAPHICAL DATA**

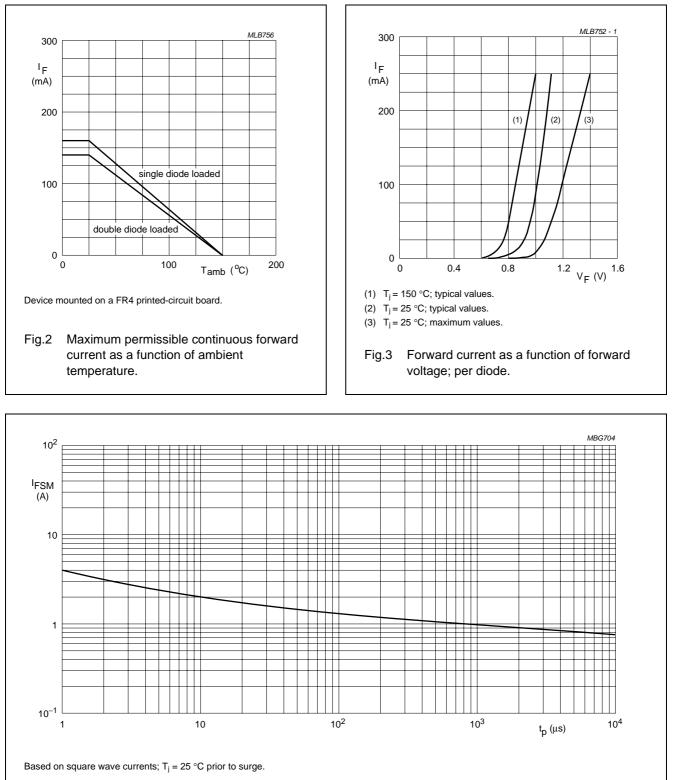
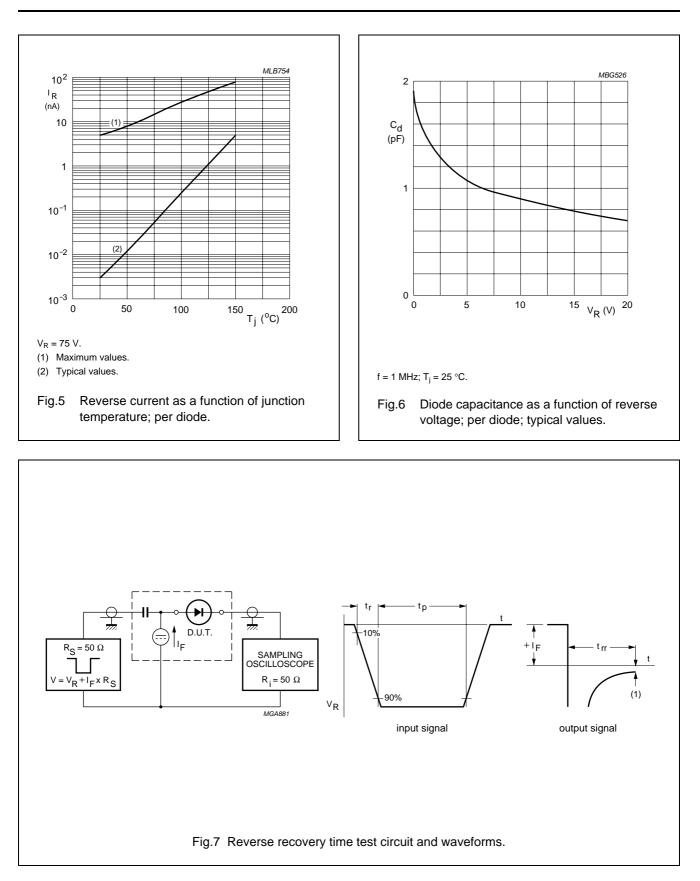


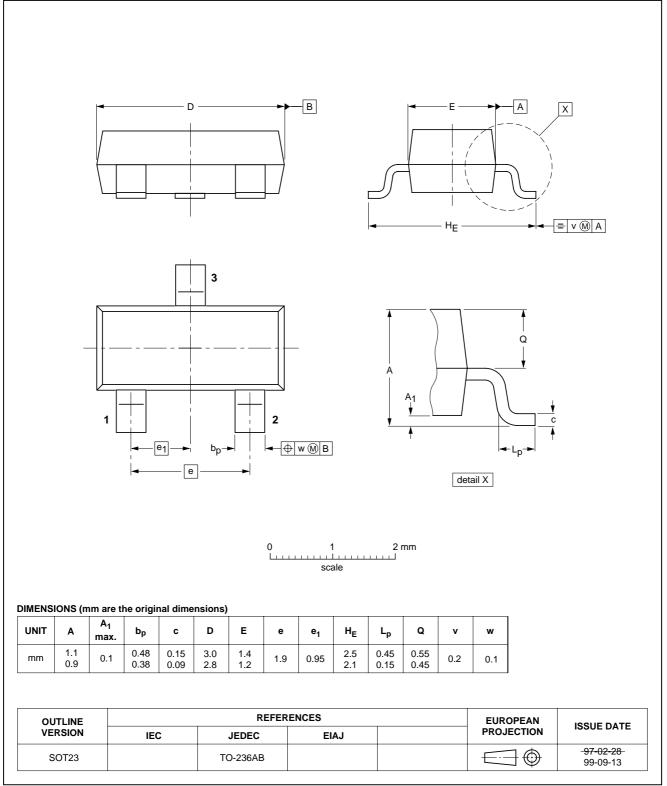
Fig.4 Maximum permissible non-repetitive peak forward current as a function of pulse duration per diode.

# BAV199



#### PACKAGE OUTLINE





BAV199

SOT23

BAV199

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### Notes

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# **NXP Semiconductors**

#### **Customer notification**

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#### **Contact information**

For additional information please visit: http://www.nxp.com For sales offices addresses send e-mail to: salesaddresses@nxp.com

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